

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Tsuyoshi FUJIWARA et al.

Appln. No.: 10/083,416

Group Art Unit: 2813

Filed: February 27, 2002

Examiner: Thang Nguyen

For: SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE AND

MANUFACTURING METHOD THEREOF

AMENDMENT

Commissioner for Patents P.O. Box 1450 Alexandria, Virginia 22313-1450

Sir:

In response to the Office Action mailed February 28, 2003, please amend the above-identified patent application BEST AVAILABLE COPY as indicated below.

IN THE TITLE:

Please change the title to read:

METHOD OF MANUFACTURING SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE COMPRISING A MEMORY CELL AND A CAPACITOR